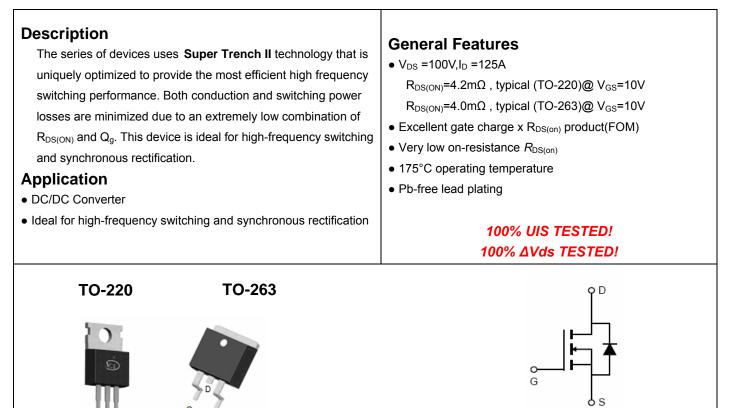


NCE N-Channel Super Trench II Power MOSFET



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP045N10	NCEP045N10	TO-220-3L	-	-	-
NCEP045N10D	NCEP045N10D	TO-263	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	Ι _D	125	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	95	A
Pulsed Drain Current	I _{DM}	500	A
Maximum Power Dissipation	PD	200	W
Derating factor		1.33	W /℃
Single pulse avalanche energy (Note 5)	E _{AS}	871	mJ
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	0.75	°C/W	
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NCEP045N10, NCEP045N10D

Electrical Characteristics (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition		Min	Тур	Max	Unit
Off Characteristics		·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA		100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V		-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,\	/ _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)		·					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =	250µA	2	3	4	V
Drain Source On State Desistance	P		TO-220	-	4.2	4.5	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =60A	TO-263		4.0	4.5	
Forward Transconductance	g fs	V _{DS} =5V,I _D	=60A		120	-	S
Dynamic Characteristics (Note4)		·					
Input Capacitance	C _{lss}	- V _{DS} =50V,V _{GS} =0V, F=1.0MHz		-	5500	-	PF
Output Capacitance	C _{oss}			-	590	-	PF
Reverse Transfer Capacitance	C _{rss}			-	25	-	PF
Switching Characteristics (Note 4)		·					
Turn-on Delay Time	t _{d(on)}			-	21	-	nS
Turn-on Rise Time	tr	V_{DD} =50V,I _D =60A, V_{GS} =10V,R _G =3Ω		-	13	-	nS
Turn-Off Delay Time	t _{d(off)}			-	40	-	nS
Turn-Off Fall Time	t _f			-	12	-	nS
Total Gate Charge	Qg	- V _{DS} =50V,I _D =60A, - V _{GS} =10V		-	92	-	nC
Gate-Source Charge	Q _{gs}			-	27		nC
Gate-Drain Charge	Q _{gd}			-	21		nC
Drain-Source Diode Characteristics	•						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =60A		-		1.2	V
Diode Forward Current (Note 2)	I _S			-	-	125	А
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =60A		-	72	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)		-	140	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

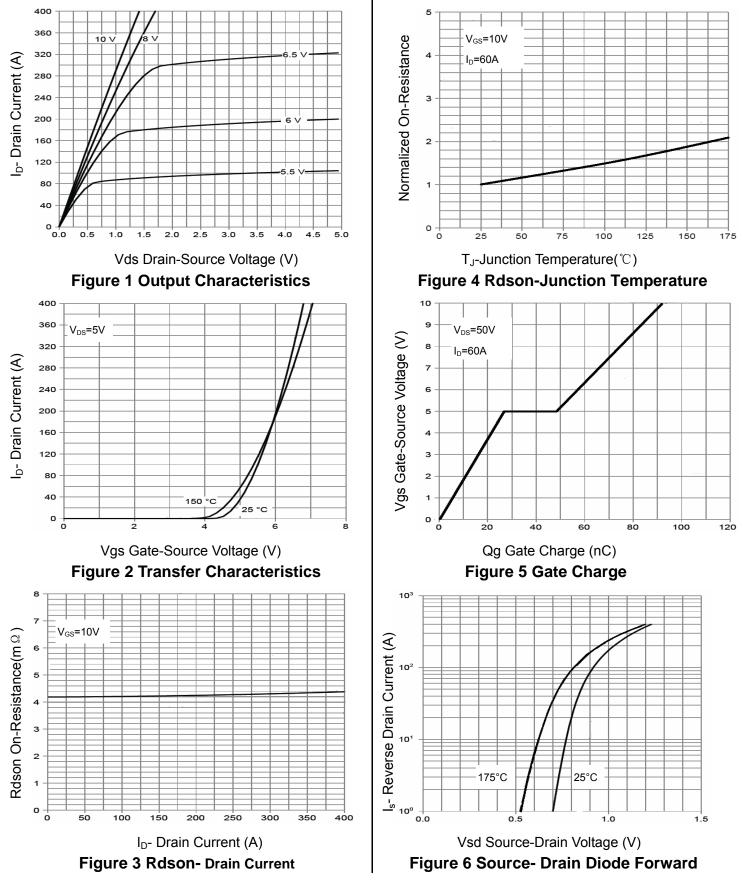
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathrm{C}$,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25 Ω



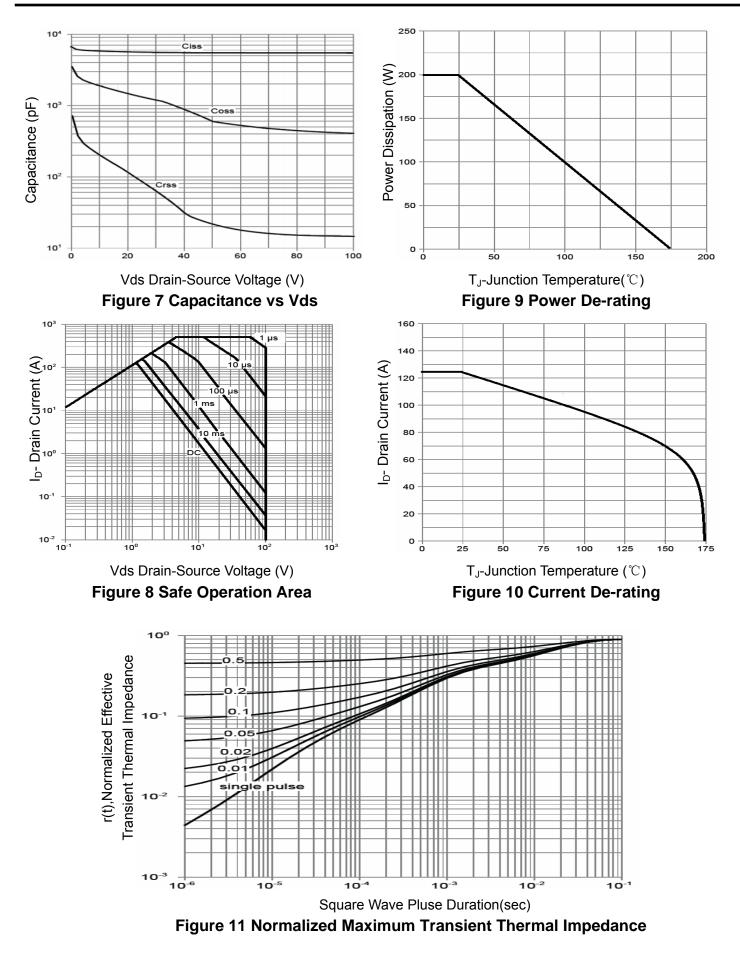
NCEP045N10,NCEP045N10D

Typical Electrical and Thermal Characteristics





NCEP045N10,NCEP045N10D

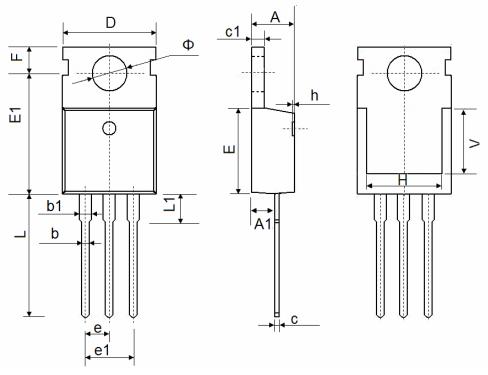


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TO-220-3L Package Information

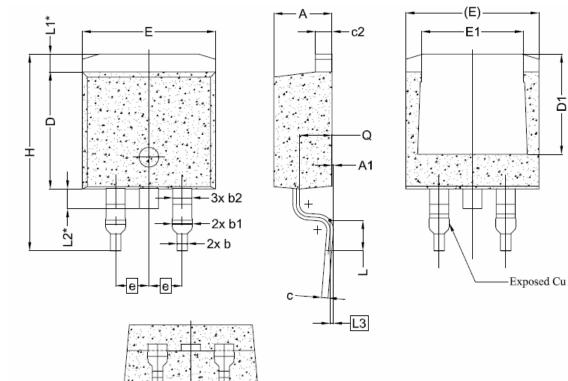


Cumhal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276	REF.	
Ф	3.400	3.800	0.134	0.150	



NCEP045N10,NCEP045N10D

TO-263-2L Package Information



Symbol	Dimensions In Millimeters					
Symbol	Min.	Nom.	Max.			
A	4.24	4.44	4.64			
A1	0.00	0.10	0.25			
b	0.70	0.80	0.90			
b1	1.20	1.55	1.75			
b2	1.20	1.45	1.70			
С	0.40	0.50	0.60			
c2	1.15	1.27	1.40			
D	8.82 8.92		9.02			
D1	6.86 7.65		-			
E	9.96 10.16		10.36			
E1	6.89	7.77	7.89			
е	2.54BSC					
Н	14.61	14.61 15.00				
L	1.78	2.32	2.79			
L1	1.36 REF.					
L2	1.50 REF.					
L3	0.25 BSC					
Q	2.30	2.48	2.70			

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